

09/681,666

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,803,318 B1
DATED : October 12, 2004
INVENTOR(S) : Qiao et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 21,

Lines 57-58, please delete "chemistries etch are" and substitute therefor -- chemistries are --.

Line 59, please delete "material silicon" and substitute therefor -- material:silicon --.

Column 22,

Line 27, please delete "he second" and substitute therefor -- the second --.

Line 56, please delete "step or" and substitute therefor -- step of --.

Signed and Sealed this

First Day of February, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office